



TAYCHIPST

HIGH EFFICIENCY RECTIFIER

ERB32-01 THRU ERB32-02

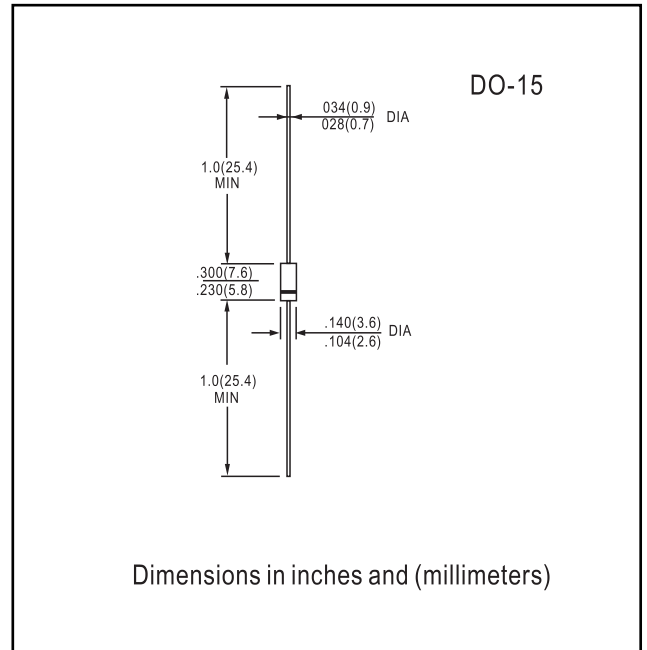
100V-200V 1.2A

FEATURES

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Freon,Alcohol,Isopropanol and similar solvents
- The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

Case:JEDEC DO--15,molded plastic
 Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
 Polarity: Color band denotes cathode
 Weight: 0.014 ounces,0.39 grams
 Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

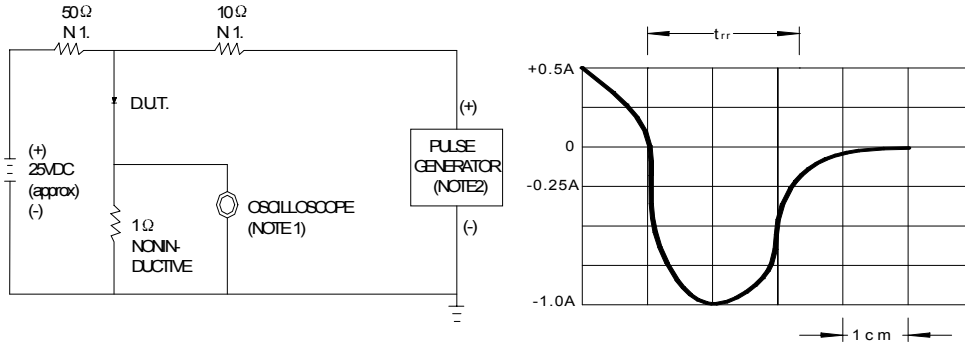
Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		ERB32 - 01	ERB32 - 02	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	V
Maximum RMS voltage	V_{RMS}	70	140	V
Maximum DC blocking voltage	V_{DC}	100	200	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	1.2		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	I_{FSM}	50.0		A
Maximum instantaneous forward voltage @ 1.2A	V_F	0.92		V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	I_R	5.0	50.0	μA
Maximum reverse recovery time (Note1)	t_{rr}	50		ns
Typical junction capacitance (Note2)	C_J	50		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50		$^\circ C/W$
Operating junction temperature range	T_J	- 55 ----- + 150		$^\circ C$
Storage temperature range	T_{STG}	- 55 ----- + 150		$^\circ C$

NOTE: 1. Measured with $I_F=0.5A$, $I_R=1A$, $I_{rr}=0.25A$.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Thermal resistance from junction to ambient.

RATINGS AND CHARACTERISTIC CURVES ERB32-01 THRU ERB32-02

FIG.1-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

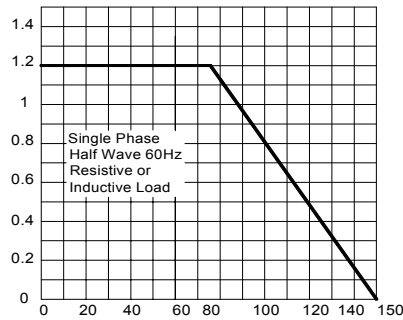


NOTES: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ. 22pF
2. RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω.

SET TIME BASE FOR 20/30 ns/cm

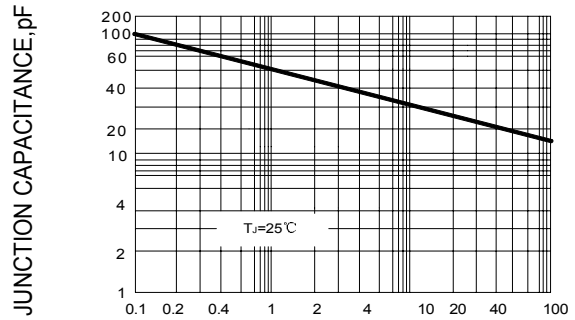
FIG.2 -FORWARD DERATING CURVE

AVERAGE FORWARD RECTIFIED CURRENT.
AMPERES



AMBIENT TEMPERATURE. °C

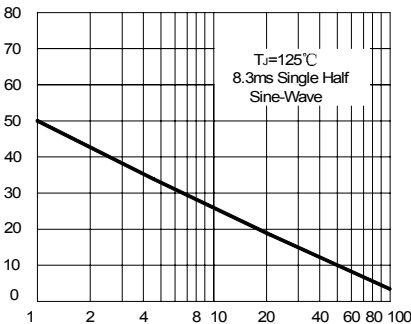
FIG.3-TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

FIG.4-PEAK FORWARD SURGE CURRENT

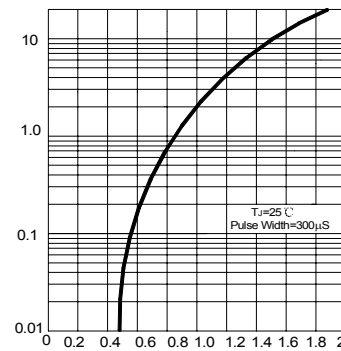
PEAK FORWARD SURGE CURRENT.
AMPERES



NUMBER OF CYCLES AT 60HZ

FIG.5 - TYPICAL FORWARD CHARACTERISTIC

INSTANTANEOUS FORWARD CURRENT
AMPERES



INSTANTANEOUS FORWARD VOLTAGE, VOLTS